20256 S/148/60/000/011/013/015 A161/A030

The effect of workhardening on the ...

The structure seen under the electronic microscope was deterogeneous (Figure 6) even without heat application after coldworking. The variations of electric resistance indicated very intensive further aging, though the dimensions of the second phase remained very disperse and much smaller (-300 Å) than in specimens left without workhardening (-700 Å). This phenomenon is apparently connected with the refining of the blocks and more uniform distribution of the second phase particles that are located not on the grain boundaries only but also on the lines of shearing and twinning. The increasing number of volumes in which a phase separation is possible results in refining of the grain. The conclusion was made that drawing raised hardness more than rolling with the same reduction. This seems to be due to the specific effect of different texture types and a more complex stress pattern in drawing. The higher 2nd-order distortions value after drawing confirms this assumption. It seems that the main factors determining the high strength of coldworked and aged specimens are: decomposition of the supersaturated solid solution with the formation of very disperse phase particles; refining of the mosaic blocks; the usual growth of the blocks in aging at 700° and decrease of the 2nd order distortions. But the intensity of these processes is low, which might be con-

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S/148/60/000/011/013/015 A161/A030

The effect of workhardening on the

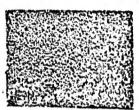
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nected with a simultaneous decomposition process and formation of phases that are splitting the blocks and raising the 2nd order distortions, i.e., with inverse processes. Coagulation of phases in workhardened specimens obviously goes on within single blocks (that stay refined for long time), mainly on account of additive separations from a solid solution. There are 7 figures.

ASSOCIATION: Moskovskiy institut stali (Moscow Steel Institute)

SUBMITTED: Febr. 25, 1960

Figure 1: Structure after quenching from 1080°C, 8 hours holding and air cooling. X 25,000.



Card 4/6

MERKIN, Roal'd Mikhaylovich; SVISTUNOVA, Galina Mikhaylovnai.

PROFERANSOV, D.P., nauchnyy red.; BOGINA, S.L., red.
izd-va; RODIONOVA, V.M., tekhn. red.

[Estimated cost of construction] Smetnaia stoimost' stroitel'stva. Moskva, Gosstroiizdat, 1962. 41 p.

(Construction industry—Costs)

YEMELIN, Ye.A.; SVISTUNOVA, G.N.; TSARFIN, Ya.A.

Simultaneous determination of sulfuric acid and phenolsulfonic acid in mixtures. Zav.lab. 28 no.5:548 '62. (MIRA 15:6)

1. Vladimirskiy nauchno-issledovatel'skiy institut sinteticheskikh smol.

(Sulfuric acid) (Phenolsulfonic acid)

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Separate determination ...

portion. Control tests showed that the presence of the nitrile group did not interfere. If MVP is contained in the copolymer in the form of salt, 200-400 mg of the copolymer are dissolved in dimethyl formamide, and potentiometrically titrated with 0.1 N piperidine dissolved in isopropanol. To determine the nitrile nitrogen, 200 mg of the copolymer are mixed with 100 ml of 40% KOH, and the ammonia released in heating is collected in 40 ml of 0.1 N HCl. After 4-5 hr, water vapor is blown through the apparatus, and the free HCl is back-titrated with 0.1 N NaOH. Table 2 shows test results in good agreement with the total nitrogen content determined according to Dumas. There are 2 figures, 2 tables, and 7 references: 6 Soviet-bloc and 1 non-Soviet-bloc.

ASSOCIATION: Vladimirskiy nauchno-issledovatel'skiy institut sinteticheskikh smol (Vladimir Scientific Research Institute of Synthetic Resins)

Card 2/3

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"APPROVED FOR RELEASE: 07/13/2001

CIA-RDP86-00513R001654210006-6

YEMELIN, Ye.A.; SVISTUNCVA, G.P.

Determination of acetic anhydride in acetylating mixtures.

Zav.lab. 27 no.8:971-972 '61. (MIRA 14:7)

1. Vladimirskiy nauchno-issledovatel'skiy institut sinteticheskikh smol. (Acetic anhydride)

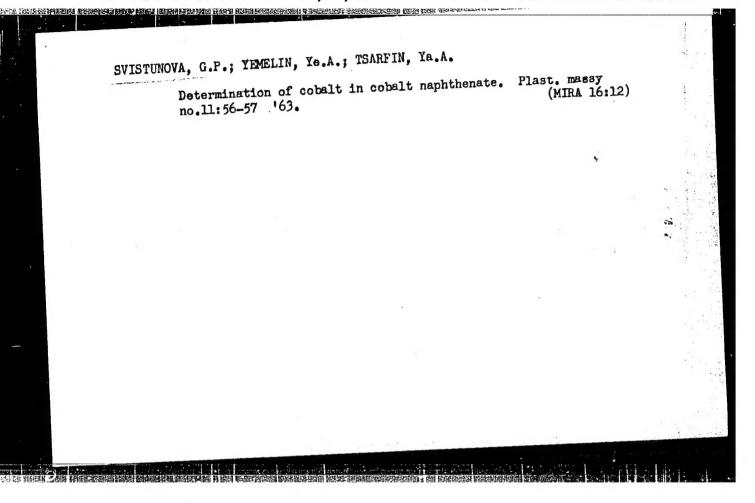
YEMELIN, Ye.A.; SVISTUNOVA, G.P.

Fotentiometric determination of acids in mixtures of cellulose acetate production. Zav. lab. 27 no. 12:1458-1459 '61.

(MIRA 15:1)

1. Vladimirskiy nauchno-issledovatel'skiy institut sinteticheskikh smol.

(Cellulose acetate) (Acids, Organic) (Potentiometric analysis)



ASD Pc-4/Pr-4 PM/WW/JW EMP(j)/EPF(c)/EMT(m)/BDS \$/2513/63/015/000/0156/0159 AT3002344 ACCESSION NR: AUTHORS: Yemelin. Ye. A.; Swistunova, G. P.; Tserfin, Ya. A. TITUE: The separate determination of the pyridinic and nitrila nitrogen in the acrylonitrile, and methylvinylpyridin copolymers. SOURCE: AN SSSR. Komissiya po analiticheskoy khimii. Trudy. v. 15, 1963. Organicheskiy snaliz, 153-159. TOPIC WAGS: nitrogen, nitrile, seponification, KDH, HOL, nitromethene, acrylonitrile, methylvinylpyridine. ABSTRACT: The determination of nitrogen in nitrile was accomplished by means of saponification with 40% aqueous ROH solution. The ammonium evolved from the reaction is absorbed in 0.1 N HCl solution and then titrated with 0.1 N NaOH solution using methyl red indicator. The saponification must be carried out in a vessel resistant to strong alkali solutions. The determination of pyrydinic nitrogen was accomplished by potentiometric non-aqueous titration. After the dissolution of methylvynilpyridine copolymer in a mixture of nitromethane and hydrochloric acid, the solution is titrated potentiometrically with 0.05 N HClO4 Card

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nitrogen. The average re	he nitrile group does not interfere lative error is 1%. Orig. art. ha y nauchno-issledovetol'skiy instit iclResearch Institute for Syntheti	s: l table. ut sintelicheskikh
SUBMITTED: 00	DATE ACQ: 13Jun63	ENOL: 00
SUB CODE: CH, ML	No ref sov: ool	OTHER: COL
Card 2/2		

YFMELIN, Ye.A.; SVISTUNOVA, G.P.

Analysis of isophthaloyl chloride. Zhur. anal. khim. 20
(MIRA 18:9)
no.9:1010-1013 '65.

l. Vladimirskiy nauchno-issledovatel'skiy institut sinteticheskikh
amol.

SVISTUNOVA, K. I., and POKROVSKIY, Ya.Ye.

"On recombination in Silicon doped by indium, potassium, and antimony."

Report to be submitted for the Intl. Conference on Photoconductivity, IUPAP, Cornell University, Ithaca, N. Y., 21-24 Aug 1961.

(Kalashnikov, S. G. is scheduled to present the paper)

9.4300 (1150,1143,1136)

20786 s/181/61/003/003/011/030 B102/B205

26.2421 AUTHORS: Pokrovskiy, Ya. Ye. and Svistunova, K. I.

TITLE:

Study of recombination in silicon alloyed with gallium,

indium, and antimony

Fizika tverdogo tela, v. 3, no. 3, 1961, 757-767

TEXT: The electron-hole recombination in semiconductors has been studied several times, but the effect of various impurities on this process has not been duly considered. Of particular interest is the effect of the elements of the third and the fifth group on the lifetime of carriers in silicon, since these elements were used to obtain silicon of a given conductivity. study has now been made of the effect of Ga, In, and Sb on the recombination of minority carriers in silicon. The starting material were single crystals of silicon, which had been obtained by zone crystallization. They had a resistivity of some hundred ohm cm; the carrier lifetime varied from 200 to 800 / sec. The specimens were cut along the growth axis (111), and had a size of 15 · 4 · 3 mm3. Minute quantities of impurities were added. The distribution coefficients for Ga, Sb, and In amounted to 0.01, 0.04, and

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5.10-4, respectively. The carrier concentration was determined from the Hall effect in direct current. The ratio of the Hall mobility to the drift mobility was 1.18 for n-type and 0.71 for p-type crystals. The carrier lifetime was determined from the vanishing of photoconductivity. Within the region of partial ionization of the acceptors, the hole concentration, Po,

is given by $\frac{P_O(N_D+P_O)}{N_A-N_D-P_O} = N_V e^{-E/kT}$, where N_A is the acceptor concentration, N_D the donor concentration, and N $_{_{\rm V}}$ the effective state density in the valence band; E is the acceptor ionization energy. If ND «NA, Po, Pc = NAN e E/2kT For In one obtains E = 0.16 ev; the activation energy for almost all specimens was equal to E/2 = 0.08 ev. This indicates that $N_D < N_A$, P_O for all

specimens. In the following, the authors report on a comparison of various specimens concerning the dependence of the minority carrier lifetime t on the majority carrier concentration, and the temperature dependence of t [Abstracter's note: The specimens studied are indicated by numbers and letters; their composition and parameters, however, are not given]. Specimens containing gallium in concentrations of more than 1016cm-3 had similar

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Card 3/5

carrier lifetimes varying from 9 to 11 µsec. The recombination rate of these specimens was determined, not by Ga, but by unchecked impurities or defects. In-doped specimens showed the same hole concentration but somewhat shorter lifetimes. The electron trapping cross section for In was not larger than 10-19 cm2. At temperatures below 200°K, all In- and Ga-doped crystals had a carrier lifetime of about 5 $\mu \rm sec$, irrespective of their impurity concentration. With a further rise in temperature, many In-doped specimens showed an exponential increase of lifetime; in this range, f was proportional to $1/p_0$. The hole capture cross section for In was found to be of the order of 10^{-15} cm². A study of the dependence of t on the electron concentration in Sb-doped specimens showed that if the concentration of Sb is changed by two orders of magnitude, ? remains practically unchanged. This is taken as an indication that Sb does not affect the recombination rate in Si. T is determined by deep unchecked recombination centers. In- or Sb-doped specimens had a lifetime of 10-12 #sec, which was largely independent of the concentration of In. A study of the temperature dependence of the time in which the photoconductivity in n-type In-doped specimens vanishes has shown a number of peculiarities. While Sb-doped specimens exhibit

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Study of ...

a slow decrease of lifetime with dropping temperature, In-doped specimens show an exponential increase of 7. The activation energy of this process was 0.16 ev. These observations may be described by the relation $t = t_p (1 + N_t/p_1^t)$, where p_1^T is the hole concentration in the case where the Fermi level coincides with the indium level; Nt is the concentration of indium. important results of these studies are the following: 1) Ga and Sb do not affect the recombination rate in Si; the carrier lifetime in Si alloyed with these elements is determined by the existence of unchecked recombination 2) The electron trapping cross section for In atoms is less than centers. 10-19 cm2, and the hole trapping cross section for In atoms is larger than 3) n-type Si alloyed with In and Sb displays adhesion effects. This may be quantitatively explained by the trapping of holes by ionized In atoms. Professor S. G. Kalashnikov is thanked for discussions and his interest in the work. There are 5 figures, 2 tables, and 12 references: 4 Soviet-bloc and 8 non-Soviet-bloc.

Card 4/5

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Study of ...

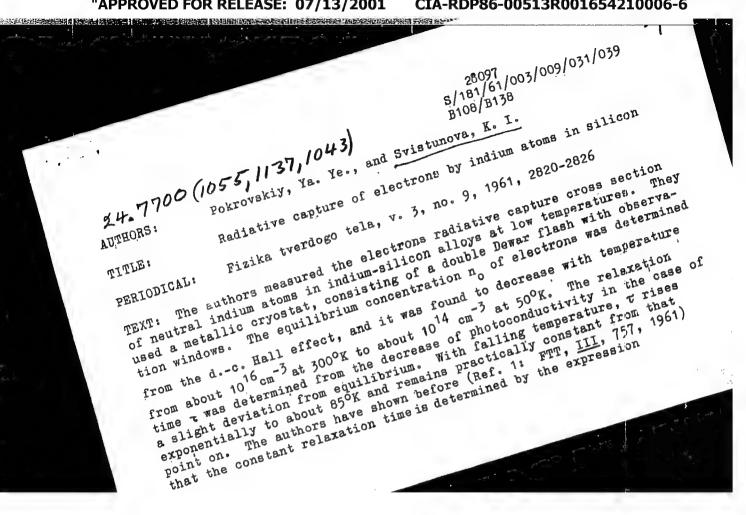
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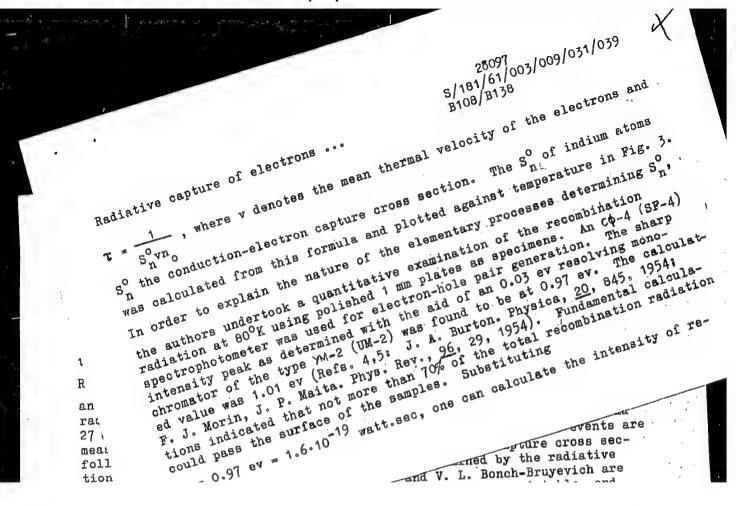
Institut radiotekhniki i elektroniki AN SSSR Moskva (Institute

of Radio Engineering and Electronics of the AS USSR, Moscow)

June 24, 1960 SUBMITTED:

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	each other	$\sum_{i} A_i e^{-\lambda t}$, $\delta p = \sum_{i=1}^{n} t$	ing approximations;		(3)
	dn = dp = card 1/5	$\Delta, \ JN_{\overline{t}} = JN_{\overline{t}} = JN_{\overline{t}} = \frac{1}{2} JN_{\overline{t}} = $	$n_0, p_1^i \gg p_0,$ $n_0, p_1^i \gg p_0,$ $n_0 \ll \alpha_n(n_0 + n_1).$ In the simplest case, $n_0 \ll n_0$		

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Attenuation of non-equilibria	\m • • •			
$N_i^0 \gg n_0 + n_1^i, N_i^-(n_0)$ $N_i^0 \gg n_0 + n_1,$ $\alpha_n^i(n_0 + n_1^i), \alpha_n(n_0 + n_1) \ll \alpha_p^i$	0/ de D. www.U10		(7)	ئىد ئ
are satisfied (p-type semice				+ √ 1
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(8).

Attenuation of non-equilibrium ...

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$$\begin{split} \lambda_1 &= \frac{1}{\tau_1} = \alpha_n N^0 + \alpha_n^t N_t^0, \\ \lambda_2 &= \frac{1}{\tau_2} = \alpha_p \left(p_0 + p_1 \right), \\ \lambda_3 &= \frac{1}{\tau_3} = \alpha_p^t \left(N_t^- + p_0 + p_1^t \right), \\ A_1 &= \Delta, \quad A_3 = 0, \quad A_3 = 0, \\ B_1 &= \Delta - B_3 - B_3, \quad B_2 = \Delta \alpha_n N^0 \frac{\lambda_3 - \alpha_p^t \left(p_0 + p_1^t \right)}{(\lambda_1 - \lambda_2) \left(\lambda_3 - \lambda_3 \right)}, \\ B_3 &= \frac{\Delta}{\lambda_1 - \lambda_3} \left[\alpha_n^t N_t^0 - \alpha_p^t N_t^- - \frac{\alpha_n N^0 \alpha_p^t N_t^-}{\lambda_2 - \lambda_3} \right], \\ C_1 &= \Delta - C_2 - C_3, \quad C_3 = \Delta \frac{\alpha_n N^0 \alpha_p^t N_t^-}{(\lambda_1 - \lambda_2) \left(\lambda_2 - \lambda_3 \right)}, \quad C_3 = B_3. \end{split}$$

This solution is well suited for describing the attenuation of photoconductivity in p-type Si, doped with In and containing several Card 4/5

Attenuation of non-equilibrium ...

S/181/63/005/001/019/064 B102/B186

10

exponential growth of $\tau(T)$ at low temperatures is determined either by (capture of holes by impurity centers) or by τ_3 (capture of holes by In atoms). n_0 , p_0 are the carrier equilibrium concentrations, f_n , f_p the deviations from equilibrium, N_{t} and N the concentrations of doping and foreign impurities, N_t^{\perp} , N^{-} the concentrations of the corresponding atoms, $N_t^0 = N_t - N_t^-$, $N_t^0 = N - N_t^-$, $\int N_t^-$ and $\int N_t^-$ are the deviations from the equilibrium populations of the investigated and foreign atoms by electrons, n_1^{t} , p_1^{t} (n,,p,) are the carrier concentrations if the Fermi level coincides with the energy level of the investigated (foreign) impurity, α_n^t , α_p^t (α_n , α_p) are the carrier capture cross sections for investigated (foreign) impurities.

Institut radiotekhniki i elektroniki AN SSSR Moskva (Institute of Radio Engineering and Electronics AS USSR, "GOO"

SUBMITTED: Card 5/5

July 21, 1962

L 15553-63 EWP(q)/EWT(m)/BDS AFFTC/ASD ACCESSION NR: AP3003883 \$/0181/63/005/007/1880/1886 AUTHORS: Fokrovskiy, Ya. Ye.; Syistunova, K. I TITLE: Some peculiarities of rediative electron capture at indium and gellium atoms SOURCE: Fizika tverdogo tela, v. 5, no. 7, 1963, 1880-1886 TOFIC TAGS: capture, radiative capture, electron, In, Ga, Si, phonon, atom, indium, ABSTRACT: It has been found that the coefficient of electron capture at neutral atoms of In and Ga in Si is near 10-12 cm3 sec-1 at 30K and that it increases exponentially on decrease in temperature, with an activation energy of about 0.035 ev. It has been established that the coefficient of electron capture at Ga atoms, as at In atoms, is determined by rediative transitions. An investigation of the spectral distribution of recombination radiation has shown that electron capture at Ga atoms occurs with an emission of phonons, whereas at In a considerable part of the capture process occurs without the accompaniment of phonons. The setup for measuring recombination radiation is shown in Enclosure 1. "In conclusion the authors express their thanks to Professor S. G. Kalashnikov for discussions of the results." Orig. art. has: 4 figures, 1 table, and 3 formulas. Card 1/1/ ASSOCIATION: Institute of Radio Engineering and Electronics, Academy of SS

ACCESSION NR: AP4011731 -

S/0181/64/006/001/0019/0024

AUTHORS: Pokrovskiy, Ya. Ye.; Svistunova, K. I.

TITLE: Radiative capture of current carriers at impurity atoms in silicon and germanium

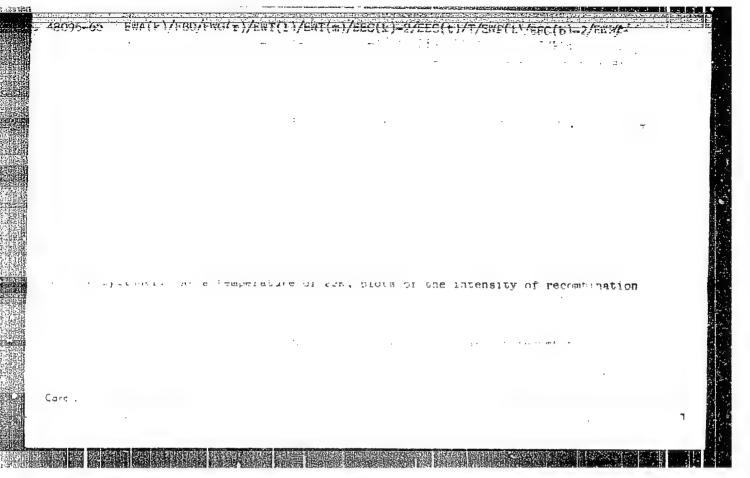
SOURCE: Fizika tverdogo tela, v. 6, no. 1, 1964, 19-24

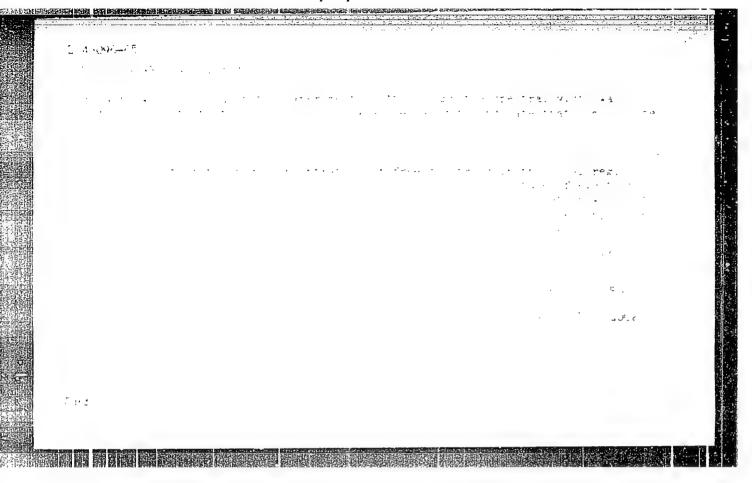
TOPIC TAGS: radiative capture, capture, current carrier, charge carrier, impurity atom, silicon, germanium, capture coefficient, electron, hole, boron, bismuth, zinc, radiative transition, recombination radiation, useful absorption, free electron

ABSTRACT: The authors have determined the temperature dependence of the capture coefficient of electrons at neutral atoms of boron and of holes at neutral atoms of bismu h in silicon; and also of electrons at singly charged negative atoms of zinc in germanium. These relations are shown in Fig. 1. on the Enclosure. The authors have found that the capture coefficient is determined by radiative transitions. In examining the connection between spectral distribution of impurity recombination radiation and deep impurity levels, they have shown that the contribution of radiative transitions, occurring without the participation of phonons, increases as the depth of level becomes greater. Because of the relative small capture coefficient,

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10 cm. At zir "useful" absorption	no concentrations of	about 10 ¹⁶ cm ⁻³ t	his makes the co	efficient of	5 15
large absorption	craction of which (ir	this experiment)	exceeds 10 cm	, leads to a	
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	and Electronics AN	SSSR)	, , , , , ,	- OT 000 OT 11	
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1 54734.65 $ENT(1)/ENP(\epsilon)/ENT(m)/ENP(1)/EMP(t)/EMP(b)$ IJP(c) JD/JG/GG 5/0181/65/007/006/1837/1845 LCCESSION NRI AF5014589 LUTHOR: Pokrovskiy, Ya. Ye.; Svistunova, K. I. 'TTTLE: Impurity and inter-impurity radiative recombination in silicon :OURCE: Fizika tverdogo tela, v. 7, no. 6, 1965, 1837-1845 which Tank . radiative recombination that conductivity, silicon, conduction band, with any for magnification and are BCTPACT: This is a continuation of earlier investigations by the authors (FTT v. which are also with the second of photoconductivity in the second of the a second of the impurity remedicant a rapidition of spirite at a population of the or boron, with an aim at courtsinging whether allowance for the direct electronic transitions between the mountly atoms of the donor and acceptors is necessary. The silicon was strongly igned to make the impority hand over so the conduction hand of the silicon, and to way the electron relating to the allocal of the name rations. To provide a low injec-The service of the service of the filter at room temto the season the court a war. end the entre the sample take fives appt to a crystet at low temperature. The .ard 1/2

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results show that at low temperatures, when the electron concentration (n) in the conduction band becomes lower than 1013 cm-3, the recombination rate is determined by the direct radiative transitions between the donor and the acceptor atoms. The reeff'gient of inter-impurity radiative recombination was found to be close to 3 x tirm & complete and to depend tittle on the temperature. When no lot come, the rememberships once a determined by capterive market of the electrons from the noticultion band by the indium on throng atoms. It is thus shown that direct electronic transitions between the donor and acceptar at was can play an important role and even determine the rate of resomblimation at low temperatures at relatively low togrection severa . At high togrection leveral movement, which were used in the eartion myestigations, capture of the free nan-equilibrium carriers by the neutral atoms of indima, gaillum, pera, and bismuth in silicon predominate. "The authors thank S. G. Kalashuikov for a ciscussion of the work Orig. art. hast S flaures and) foresalas.

ASCOCIATION: Institut radiotekbniki i elektroniki AN SBSR, Moscow (Institute of Radio Engineering and Electronics, AN SRSN)

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> ACC NR. AP5027451

SOURCE CODE: UR/0181/65/007/011/3464/3465/6/2

44,55 AUTHOR:

44:55 Pokrovskiy, Ya. Ye.; Svistumova, K. I.

ORG: Institute of Radio Engineering and Electronics AN SSSR, Moscow (Institut

radiotekhniki i elektroniki AN SSSR)

TITLE: Effect of doping on the recombination radiation of diodes with an n-GaSb base region

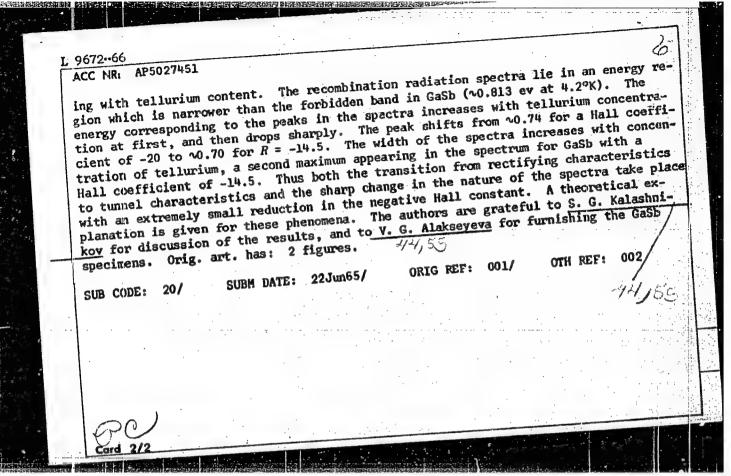
SOURCE: Fizika tverdogo tela, v. 7, no. 11, 1965, 3464-3465

TOPIC TAGS: gallium compound, antimonide, tellurium, semiconductor diode, recombination radiation, radiation spectrum

21, 44, 5 ABSTRACT: The authors study recombination radiation spectra of GaSb diodes as a function of tellurium concentration in the base region. The p-type emitter regions of the specimens were zinc-doped to a concentration of $vl \cdot 10^{20}$ cm⁻³. The Hall constant at room temperature was used for determining the tellurium content in the n-type base region. Current-voltage curves are given as well as curves for the spectral distribution of recombination radiation. Diodes with a Hall constant of -76 show a typical rectifying current-voltage curve, while the curve for diodes with a Hall coefficient of -14.5 is characteristic of tunnel type diodes. Diodes with intermediate concentrations of tellurium have rectifying characteristics, the reverse currents increas-

Card 1/2

> APPROVED FOR RELEASE: 07/13/2001 CIA-RDP86-00513R001654210006-6"



SHAPOVALENKO, B.I.; SVISTUNOVA, N.M.; CHUVILO, B.V.

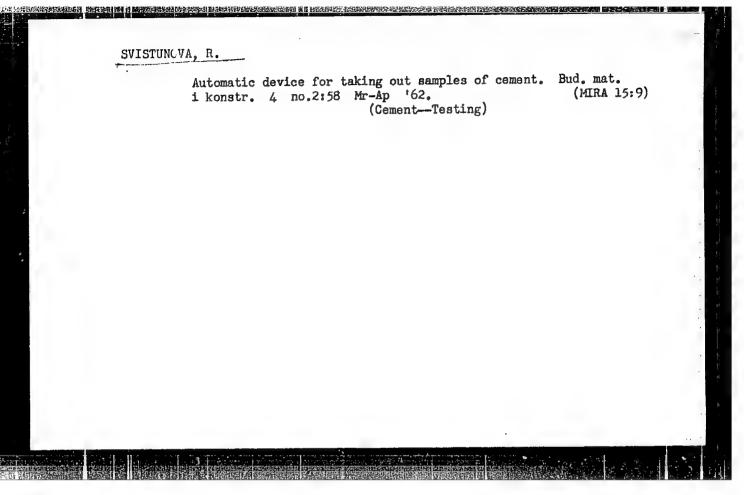
Anticorrosion technique in the production of synthetic

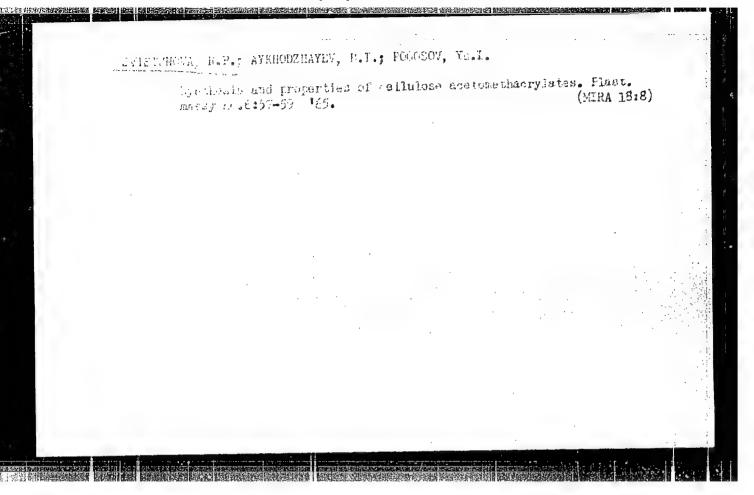
Anticorrosion technique in the production of synthetic odorous substances. Masl.-zhir.prom. 26 no.4:37-41 Ap *60. (MIRA 13:6)

1. Kaluzhskiy kombinat sinteticheskikh dushistykh veshchestv.

(Kaluga--Odorous substances)

(Corrosion and anticorrosives)





SVISTUNOVA, T.M.

Results of contact radiotherapy of epidermal hemangiomas in children; 3-year observations. Med. rad. 8 no.10:37-42 0 '63. (MIRA 17:6)

1. Iz onkologicheskogo otdeleniya 2-v detskoy polikliniki (glavnyy vrach V.I. Troshina, nauchnyy konsul'tant - doktor meditsinskikh nauk A.P. Lazareva) Kuybyshevskogo rayona Leningrada.

SVISTUNOVA, T.M. (Leningrad, ul. Blokhina, d.2/77, kv.48)

Comparative evaluation of the results of short-focus roentgenotherapy in hemangiomas of the outer integuments in children immediately following the treatment and three years later. Vop. onk. 10 no.7:83-87 (MIRA 18:4)

1. Iz onkologicheskogo otdeleniya 2-y detskoy polikliniki Kuybyshevskogo rayôna Leningrada (glavnyy vrach - V.I.Troshina, nauchnyy konsul*tant - doktor med. nauk A.P.Lazareva).

23900

The effect of rare earth metals on ... S/129/6 '000/010/002/012 E193/E135

plasticity of the alloy at high temperatures decreases. the mechanical properties of the alloy at room temperature nor its grain size is affected by the addition of the elements studied in 4) Ductility of the alloy at 700 °C quantities less than 0.1%. can be improved by rare earth metal additions. This is illustrated in Fig. 1, where the elongation (%) in creep at 700 °C under a stress of 36 kg/mm² (left-hand side scale, lower curves) and elongation during a standard tensile test at this temperature (right-hand scale, upper curves) is plotted against the actual La or Ce content in the alloy. It will be seen that all these curves pass through a maximum at approximately 0.02% of the alloying addition content. 5) The higher the melting point of the rare earth metal addition, the more pronounced is its effect on the high-temperature strength of the alloy studied. This is shown in Fig. 2, where the time-to-rupture (hours) is plotted against the nominal La, Pr, Ce and Nd content in the alloy, tested at 700 °C under a stress of 36 kg/mm². 6) The gas content of the alloy studied is reduced 3 to 4 times by the addition of 0.05-0.15% Pr or Ce. N.N. Scrokina, N.G. Moreyn, Ye.A. Balasheva and V. Golubeva participated in this work. Card 2/4

L 18729-63 EWP(q)/EWT(m)/BDS AFFTC/ASD Pad JD/HW/JG ACCESSION NR: AP3004785 S/0129/63/000/008/0027/0033 68

AUTHOR: Svistunova, T. V.; Estulin, G. V.

TITLE: Fine structure of KhN77TYu alloy containing rare-earth metals /

SOURCE: Metallovedeniye i termicheskaya obrabotka metallov, no. 8, 1963, 27-33

TOPIC TAGS: heat-resistant nickel-base KhN77TYu alloy, AISI Nimonic 80, fine transgranular structure, internal friction, chromium atom diffusion mobility, heat resistance, cerium addition, lanthanum addition, neodymium addition

ABSTRACT: The effect of 0.1% additions of Ce, La, Nor Nd (residual content 0.0%) on the fine structure of heat-resistant Ni-base KhN77Tfu [AISI Nimonic 80] alloy has been studied. Measurements of the internal friction in the 20-800C range performed on alloy containing Ce or La annealed at 1200 or 1080C and aged at 700C for 6 or 50 hr showed that both Ce and La lower the absolute magnitude of the internal friction peaks, La being more effective than Ce. In accordance with this, both Ce and La improve the heat resistance. For example, at 700C the internal friction of unalloyed KhN77TYu is 1.5 times higher and the rupture life (50 hr under a stress of 36 kg/mm²) 4 times shorter than those of the same alloy

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L 18729-63

ACCESSION NR: AP3004785

4

containing La (rupture life 220 hr). Additions of Nd were found to reduce the size of the mosaic blocks. La and Nd also lower the diffusion mobility of Cr atoms, Nd being more effective than La. High-temperature stress-rupture tests showed that the lower the diffusion mobility of Cr atoms, the higher the heat resistance of the alloy. For example, KhN77TYu alloy containing 0.1% Nd at 7000 under a load of 36 kg/mm² has a rupture life of 260 hr, compared with 50 hr for KhN77TYu alloy. In general, the higher the melting temperature of a rare-earth metal of the Ce subgroup (Nd, 1024C; La, 935C; Ce, 840C), the stronger is the beneficial effect on heat resistance. Orig. art. has: 3 figures and 1 table.

ASSOCIATION: TENTICHM

SUBMITTED: 00

DATE ACQ: 06Sep63

ENCL: 00

SUB CODE: MA, ML

NO REF SOV: OLO

OTHER: 009

Card 2/2

SVISTUNOVA, T.V.; ESTULIN, G.V.

Effect of rare earth metal additions on the oxidation of the KhN77771 alloy. Shor. trud TSNIICHM no.35:5-10 '63. (MIRA 17:2)

L 5889-65 EPA(s)-2/EMT(m)/EMP(q)/EMP(b) Pad/Pt-10 ASD(a)-5/ESD(gs) JD/

ACCESSION NR: AR4044234

5/0137/64/000/006/1088/1089

SOURCE: Ref. zh. Metallurgiya, Abs. 61509

66

AUTHOE: Estulia. V. G.: Svicturova. T. V.

TIPLE: The influence of rare-earth elements on the structure and properties of https://doi.org/10.1007/journal.com/

17 23

CITED SOURCE: Sb. Legirovaniye staley. Kiyev, Gostekhizdat USSR, 1963, 151-155

TOLIC TAGS: nickel based alloy, chrome containing alloy, rare earth, rare earth element

TR/NSLATION: Studies the behavior of rare-earth metals in the process of smelting, for hat are of their distribution in the alloy, and the influence of rare-earth metals on the structure of a solid metal. An investigation was conducted using the array himp? (0.05-0.05% 0, 21% Or, 2.5-2.8% Ti, 7.8-1.0% Al, the rest - Ni). Incividual additions of Ce. La, and Nd, and mischmetal were introduced in an amount of is. As a result of exidation, the amount of rare-earth metal in the melt

Card 1/2

L 6389-55

ACCESSION NR: AR4044234

decreases by 30-50% in 1 minute and by 80-90% in 9 minutes. The plasticity and heat resistance of the alloy are sharply lowered after the first minutes of holding of the melt with the rare-earth metal. An increase of the holding to 6-9 min leads at first to a restoration, and then to an essential increase, of these pro erries. Thus, the time of destruction of the alloy at 700° and a load of 23 lg/mm2 to 250 hours; as a result of the introduction of mischastal and holding of the melt for 1 min it drops to 40-50 hours, while with an increase of the holding to 9 min it increases to 950 hours. It is established by rediography that a large part of the rare-earth metal is in the alloy in the form of oxides, sullide, nitrides, and others. With an increase of the folding of the melt these inclusions emerge to the surface and become slag. By autoradiography it is established that the care-earth metal is distributed in the structure in the form for the inclusions throughout the grain (with a rare-earth-metal content of €0.026). With a higher content of rare-earth metals the inclusions formed by them are located for the most part along the grain boundaries, which leads to a, worsening of the properties. Mbliography: 7 references.

SUB CODE: FM. IC

ENCL: 00

Card 2/2

SVISTUNOVA, T.V., inzh.; ESTULIN, G.V., doktor tekhn.nauk, prof.

THE CHARLES OF THE CHARLES SOUR MEASURES CONTRACTORS C

Effect of rare-earth elements on the properties of nickel-base heatresistant alloys. Stal' 23 no.9:835-838 S '63. (MIRA 16:10)

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AUTHOR: Estulin, G. V. (Deceased);		A CHARLES
TIT'E: Effect of Thenium and iridium of dames	on the properties of heat-resistant nickel	E Carlotte
SOURCE: AN SSSR. Nauchny*y sovet po p	probleme zharoprochny*kh splavov.	The second
Nanka, 1964, 194-195		The second second
TOPIC TAGS: KhN7/TYu alloy, nickel bas containing alloy, molybdenum containing containing alloy, aluminum containing	se alloy, rhenium contsining alloy, iridium g alloy, chromium containing alloy, titamium alloy	
ABSTRACT: Two series of alloys, based	on Khu77TYa alloy (0.01x C, 20.2x Cr.	N. S. C.
2.52 Ti, 0.8% Al, balance N1) and cont	aining 2-6% rhenium and 3-5% iridium, pacity induction furnace, forged into bars, pacity induction furnace, forged into bars, pacity approximately for 16 hr. Both elements	The second
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5 11979-65

ACCESSION NR: AT4046841

temperature from 700 to 750—800C. Alloying with 1.5—1.8% rhenium or iridium increased the rupture life at 700C under a stress of 40 kg/mm² to about 180 hr as compared to about 40 hr for alloys containing similar amounts of molybdenum or ungsten (see Fig. 1 of the Enclosure). Rhenium and iridium, like molybdenum 7/mm range en. Strenzisch the interat man amounts in the nickel-chromium-based solid

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SUB-HITTED: 16Jun64

ENCL: 01

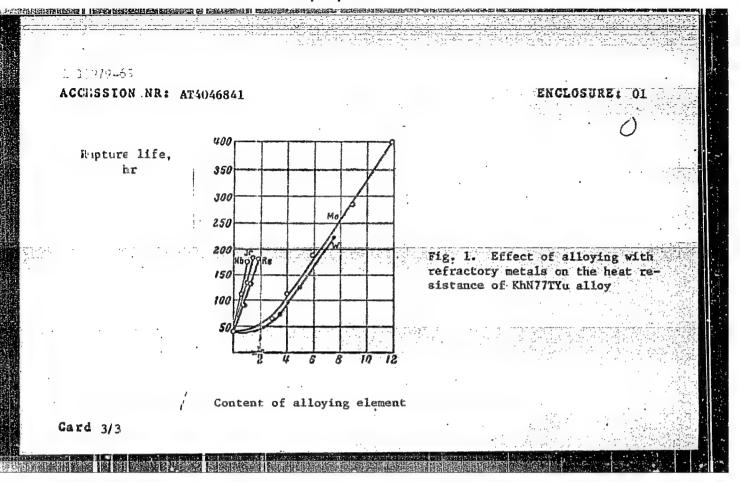
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OTHER: 000

ATD PRESS: 3137

Card 2/3



L 6615-65 EAT(m)/SAP(q)/EAP(b) MIK/JD/IM S/0126/64/018/001/0150/0153 ACCESSION NR: 1.P4042812 AUTHOR: Svistupova, T. V.; Estulin, G. V. (Deceased) TITLE: Effect of rare-earth metals, on the structure and properties of lickel KhN77TYu alloy Fizika metallov i metallovedeniye, v. 18, no. 1, 1964, SOUTCE: 150-153 TOPEC TAGS: heat resistant nickel alloy, KhN77TYu alloy, lanthanum concaining alloy, neodymium containing alloy, praseodymium containing allow, alloy structure, alloy mechanical property ABS' FACT: The heat resistant and mechanical properties of a nickelbase KhN//TYu altoy (0 02% C, 20% Cr, 2.6% Ti, 0.95% Al) with and without individual additions of 0.1% La, Nd, or Pr have been investigated. It was found that during aging at 7000, decomposition of the sol'c solution of heat treated KhN77TYu alloy is accompanied by the presipitation of a strugthening y -phase of the Nig(Ti,Al) type. The amount of the Nig(Ti,Al) phase was the same in all alloys after Card 1/4

L 6615-65 ACCESSION NR: AP4042812

identical heat treatment and increased as the duration of aging was increased. For example, after aging at 7000 for 16 and 1000 hr, the amount of the phase was about 7 and 10%, respectively. The presence of La, Nd, or Pr in the alloys has no effect on the lattice constant of either the solid solution or the precipitated phase. The hardness of an alloy with or without the addition of La, Nd, or Pr changed similarly; it increased with aging for up to 250 hr, but decreased with a longer aging time because of coagulation of the y -phase. mech.nical properties of identically heat-treated alloys containing the same amount of the Ni3(Ti,Al) phase, with or without the addition of Le, Nd, or Pr, change differently with prolonged aging. For example, aging at 700C for periods up to 100 hr has no appreciable effect on the tensile and yield strengths of the alloy but decreases its ductility characteristics. The decrease is more pronounced in an alloy without an r-e metal constituent. The addition of r-e metals stabilizes the alloy structure. At 700C, an increase in the aging time from 16 to 100 hr decreased ductility by 30% in an alloy without an r-e metal constitutent and by 12% in an alloy with La. R-e metals produced an analogous effect on the ductility of the alloys

Card : /4

L 6615-65
ACCESSION NR: AP4042812

following a 200-hr aging under a stress of 30kg/mm² at 700c. For example, the ductility of KhN77TYu alloy without an r-e metal constituent ared under stress decreased by 60%, and that with added La or Pr decreased by 30% as compared with the initial ductility of the heat-treated alloy. As the aging time was increased from 16 to 100 hr, the rupture life of alloys with added La, Nd, or Pr remained the same, but decreased by 25% in the alloy without an r-e metal constituent. The above data makes it possible to conclude that small additions of r-e metals stabilize the properties of the alloys at some stage of the aging, and that stabilization results from a different behavior of the intermetallic y -phase during prolonged aging of alloys with and without r-e metal constituents. Orig. art. has: 2 figures and 3 tables.

ASSOCIATION: Institut kachestvennykh staley TsNIIChM im. I. P. Bardina (Institute of Special Steels, Central Scientific Research Institute for Ferrous Metallurgy)

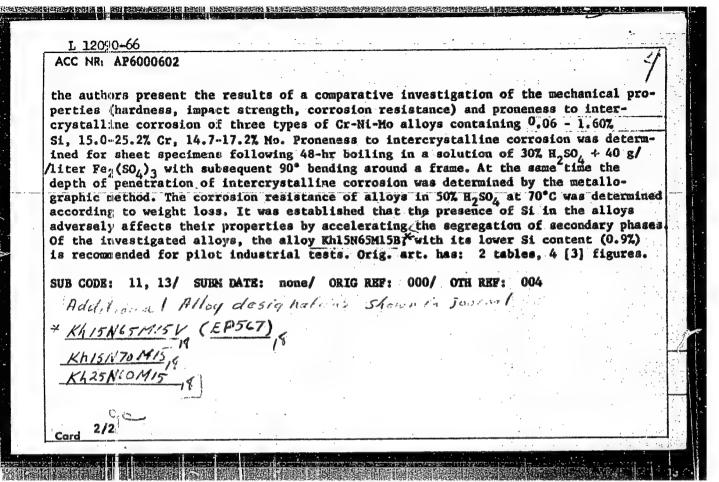
Card 3/4

L 6615-65
ACCESSION NR: AP4042812

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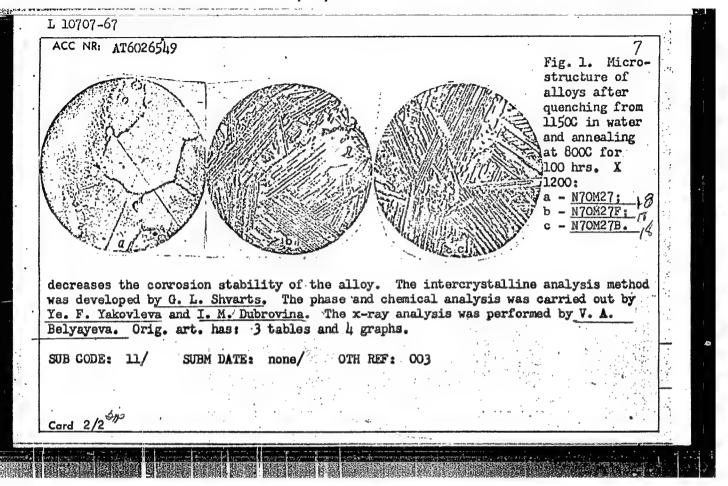
SUB CODE: MM NO REF SOV: 005 OTHER: 000

E-PERFECTED PRODUCTION AND AND ADDRESS OF THE PROPERTY OF THE PERFECT OF THE PERF MJW/JD/HW/WB IJP(c) SOURCE CODE: UR/0129/65/000/012/0006/0010 ACC NR: AP6000602 63 AUTHOR: Babakov. TITLE: Effect of silicon on the mechanical properties and proneness to intercrystalline corrosion of chromium-nickel-molybdenum alloy
27 27 27
SOURCE: Metallovedeniye i termicheskaya obrabotka metallov, no. 12, 1965, 6-10 bottom half of insert facing p. 40, and top half of insert facing p. 41 TOPIC TAGS: nickel base alloy, corrosion resistance, intercrystalline corrosion, phase diagram metal grain structure / EP375 type Cr-Ni-Mo alloy ABSTRACT: Cr-Ni-Mo alloys of the Khl5N55M16V (EP375) btype (>0.08% C, 1% Si, 1% Mn, 0.020% S, 0.025% P, 0.35% V, 7% Fe, 2.5% Co, 14.5-16.5% Cr, 15-17% Mo (Ni base)) -hastellog, langaloy, etc. -- are used in chemical industry in redox media and various aggressive media. Their principal shortcoming is proneness to intercrystalline corrosion in the zone of the thermal influence of welding as well as following reheating to 650-1000°C, due chierly to the segregation of the ternary o-phase along grain boundaries. Glass et al. (Metallkunde, 1960, no. 5)showed that reducing the Sircontent of these alloys to hundredths of a percent can retard the segregation rate of o-phase in Ni-Cr-MO alloys of the 25% Cr-15% Mo system. In this connection, the UDC: 620.17:669.018.5



ACC NRi AP6027298 E	OURCE CODE: UR/O	133/66/000/008/0746	3/0751 65	-
UTHOR: Svistunova, T. V.; Doronin, V. Ya.; Vinogradov, Yu. V.; Chermenska	. M.; Kruzhkov, V ya, N. F.; Kordon	. I.; Topilin, V. V	V.; Dzugutov,	_
RG: "Elektrostal" Plant (Zavod "Ele	ktrostal'"); TsNI	IChM .		* * * * * * * * * * * * * * * * * * * *
ITLE: Corrosion resistant nickel-bas	ed alloys			\$ P
OURCE: Stal', no. 8, 1966, 748-751	·	.•		****
OPIC TAGS: corrosion resistant alloy atigue strength	, intergranular co	orrosion, nickel be	ase alloy,	- m - to milion - m
BSTRACT: The authors study and compaickel-based alloys. The welded joint orrosion in aggressive media. Method	s of these alloys sare discussed for	are subject to into or eliminating this	tercrystalline s phenomenon.	de en en transporter des des des des
mons these methods are heat treatment ron content in the alloys and the int ound that intercrystalline corrosion ith 1.4-1.7% vanadium. This eliminat	roduction of carb: could be eliminate	ide-forming element ed by alloying N70	ts. It was	August . and bearing at the a
up to 6 mm thick without requiring head t was also found that intercrystalling cickel-molybdenum alloys by reducing the	t treatment. The e corrosion could	new alloy is designed be eliminated in	gnated EP496.	and in equip of a continues.
Card 1/2		IDC:	669.14.018.8	

L 09250-67 ACC NR: AP6027298 alloy is designated EP567. Both of these new alloys have a fatigue limit of 5-7 kg/mm2 at 1200°C which is 3-4 times higher than that of Kh18N9T steel. A new process is developed for melting and pressure working these alloys to satisfactory deformability. EP496 and EP567 alloys are melted in open induction furnaces with 500 and 1000 kg capacity. The ingots are worked on snagging machines until all defects are removed from their surfaces. Both alloys are difficult to machine, nevertheless, they can be roughed with much less difficulty than Kh18N1OT steel. Deformation temperatures for both alloys are given. Both of these alloys have excellent corrosion resistance in hydrochloric and sulfuric acids at various temperatures and concentrations. The welded seams of these alloys are not subject to intercrystalline corrosion and therefore can be recommended for welded sheet structures and tubes used in the chemical and petroleum industries. Orig. art. has: 6 figures, 2 tables. 75 SUB CODE: 11/ SUBM DATE: None/ ORIG REF: 003/ OTH REF: 005



SANDLER, N.L.; SVISTUNOVA, V.I., vrach-ordinator

Peculiarities in the clinical course of influenza in the period of outbreak in 1957 and 1959 as revealed by material from the Mogilev Province Hospital. Zdrav. Belor. 6 no. 5:31-32 My 160.

(MIRA 13:10)

1. Iz Mogilevskoy oblastnoy bol'nitsy (glavnyy vrach - zasluzhennyy vrach ESSR S.T. Il'in). 2. Zaveduyushchiy infektsionnym otdeleniye (for Sandler). 3. Infektsionnoye otdleniye Mogilevskoy oblastnoy bol'nitsy. (for Svistunova).

(MOGILEV PROVINCE—INFLUENZA)

SNEGOVSKIY, F. P., kand. tekhn. nauk; POTAPKINA, N. P., inzh.

SVISTUNOVA, V. P., inzh.

New materials used in friction units of machinery. Vest.
mashinostr. 42 no.12:36-37 D '62. (MIRA 16:1)

(Machinery—Construction)

SVISTUNOVA, Z.V., Cand Tech Sci -- (diss) "Effect of cold hardening on the structure and properties of the nickel-chrome heat-resistant alloy EI-h37." Mos, 1958, 10 pp including cover (Min of Higher Education USSR. Mos Order of Labor Red Banner Inst of Stell im I.V. Stalin) 120 comies (KL, 27-58, 112)

- 1년 -

SOV/32-24-9-21/53 Svistunova, Z. Y., Chaporova, I. N., Vasil'yeva, N. P., Sultanyan, T. A., Kiselev, V. Ye. AUTHORS:

An Electron-Microscopic Investigation of the Structure of Powder-Metallurgical Hard Alloys (Elektronnomikroskopichesk: je TITLE:

issledovaniye struktury metallokeramicheskikh tverdykh splavov)

Zavodskaya Laboratoriya, 1958, Vol. 24, Nr 9, pp 1093-1095 PERIODICAL:

(USSR)

In this paper experimental results obtained by employing new methods of producing replicas for structural examinations of ABSTRACT:

hard alloys are given. Furthermore, the conditions for polished section etching are determined. The polished sections

of hard alloys of the types BK 6, BK 8, BK11, T15K6 and T30K4 were produced as usual, the method of polishing by etching being employed. The reagents used and the conditions are given

in a table. It is observed that satisfactory results are obtained by titanium and collodion replicas. Quartz replicas have the disadvantage of being non-resistant. Among other

facts the results mentioned show that the alloys of tungsten

carbide with cobalt, a normal carbon content provided, consist Card 1/2

An Electron-Microscopic Investigation of the Structure SOV/32-24-9-21/53 of Powder-Metallurgical Hard Alloys

of two phases- the tungsten carbide and the solid solution of tungsten and carbon in cobalt. The fine-grained alloy BK consists of tungsten carbide granules of 0,4 to 0,7 μ . Pictures of the microstructures obtained are given. There are 4 figures, 1 table, and 8 references, 6 of which are Soviet.

ASSOCIATION: Vsesoyuznyy nauchno-issledovatel'skiy institut tverdykh splavov (All-Union Scientific Research Institute of Hard Alloys)

Card 2/2

SVISTUNOVA, 7... kand.tekhn.nauk

"Temper and strain aging of carbon steels" by K.M. Pogodina—
Alekseeva. Reviewed by Z.Svistunova. MTO 2 no.7:62-63 Jl '60.

(MRA 13:7)

(Steel--Metallography)

(Pogodina-Alekseeva, K. M.)

82719

\$/133/60/000/004/008/010 A054/A026

18 1120

AUTHORS:

Bernshteyn, M.L.; Svistunova, Z.V., Candidates of Technical

Sciences

TITLE:

The Effect of Cold Hardening on the Structure and the Proper-

ties of the 3N437 (EI437) Grade Heat-Resisting Alloy,

Stal', 1960, No. 4, pp. 358 - 362 PERIODICAL:

The structural changes of the EI437 type alloy during cold treatment, aging and the mechanism of strengthening are discussed. A nickel-chrome alloy, EI437, with the following composition was tested: C 0.075%; Mn 0.22%; Si 0.47%; S 0.0047%; P 0.009%; Cr 20.52%; Ce 0.04%; Ti 2.62%; Al 0.56%; Cu 0.02%; Fe 0.001%; Ni res. The alloy was rolled and drawn to harden it, quenching was started at 1,080°C, cooling was carried out by water, air and in the furnace (between 1,080 - 700°C: 125°C/h and up to 500°C: 40 - 50°C/h). After quenching and deformation the samples were repeatedly heated up to 500°C, 600°C, 700°C and 800°C for holding times up to 50,000 min, with compressions of 5%, 25%, 50% and 75%. The effect of various factors on the hardness and the electrical resistance of the alloy

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82719 S/133/60/000/004/008/010 A054/A026

The Effect of Cold Hardening on the Structure and the Properties of the 3M437 (EI437) Grade Heat-Resisting Alloy

were analyzed in detail. It was found that the hardness of the alloy grows in each case of deformation in proportion to the degree of hardening, on account of the desintegration of the blocks, the increase in secondary distortion and the decomposition of the solid solution. The changes in hardness and electrical resistance observed at 500°C indicate that the decomposition of the solid solution starts already at this temperature. The increase in electric resistance is more pronounced in the samples deformed than in those not deformed due to the formation of atomic segregations in the solid solution. This increase depends on the rate of previous deformation, its accumulated energy contributing to the development of heterogeneity in the solid solution upon repeated heating. The electrical resistance is stabilized after a holding time of 5,000 min indicating two simultaneous processes: the decrease in electric resistance during the decomposition of the solid solution will be compensated by an increase upon the formation of heterogeneity, similarly to the phenomenon observed in "natural" aging. At 600°C the formation of heterogeneity in the solid solution and aging is more

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Card 2/4

82719 \$/133/60/000/004/008/010 A054/A026

The Effect of Cold Hardening on the Structure and the Properties of the 9M437 (EI437) Grade Heat-Resisting Alloy

intensive than at 500°C. At a compression of 75% a decrease in hardness could be observed by a partial recrystallisation during a long heating interval. At 700°C hardness and electric resistance display a change which is characteristic of dispersion hardening. In samples considerably deformed high and stable values for hardness were observed. At a compression of 50% the hardness does not decrease, not even for a holding time of 50,000 min. According to X-ray analyses, the secondary distortion partially decreases when increasing the heating time at 700°C. When heating for 50,000 min, these distortions, as well as the indices for hardness, are identical for samples treated by rolling and drawing. Electron-microscopical tests proved that the high degree of hardness in samples compressed to 50% after a long aging is due to the maintenance of a highly dispersed condition of the second phase. The drop in hardness after 50,000 min is not only due to the coagulation of the second phase, but also to the beginning of recrystallization which is mainly remarkable in samples compressed to 75%. At 800°C decomposition, coagulation of the second phase and the recrystalliza-

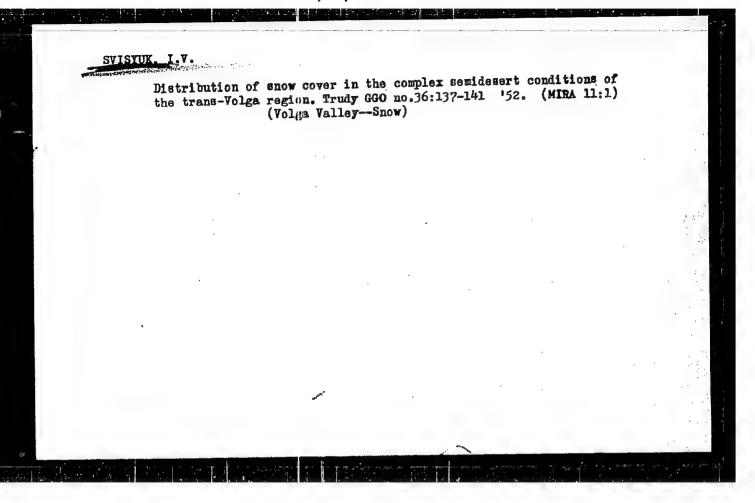
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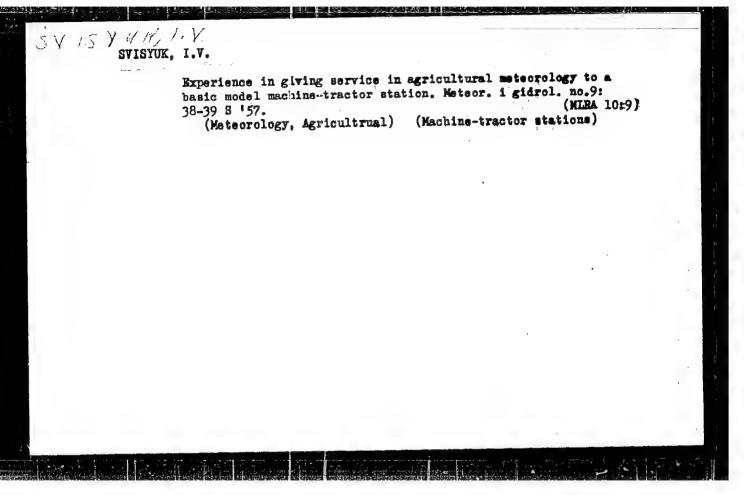
82719 S/133/60/000/004/008/010 A054/A0/26

The Effect of Cold Hardening on the Structure and the Properties of the 3M437 (EI437) Grade Heat-Resisting Alloy

tion are still more pronounced. The decrease in hardness due to coagulation and recrystallization sets in the earlier, the greater the compression. The X-ray analysis of electrolytical deposits discovered in samples compressed to 50% and 75%, after aging for 30,000 min at 800°C, showed that hardning with the accumulation of surplus energy promotes the transformation of the cubic face-centered, metastable y'-phase into a more stable n-phase (Ni₃Ti type) with hexagonal lattice. It can be concluded that the recrystallization of the cold-hardened EI437 alloy results at a long and repeated treatment at 700°C in the lecrease of heat-resistance at this temperature. When heat treatment is carried out at 600 - 650°C, where the strengthening effects of tempering can still be maintained, the heat-resistance of the metal increased after the thermo-mechanical treatment. There are 7 figures, 1 table and 9 references: 8 Soviet and 1 German.

Card 4/4





CIA-RDP86-00513R001654210006-6 "APPROVED FOR RELEASE: 07/13/2001

USSR/Cultivated Plants - Grains

M

: Ref Zhur Biol., No 12, 1958, 53541 Abs Jour

Author Svisyuk__/.I.

Petrovsk Agricultural Meteorological Station Inst

Agrometeorological Conditions of Development of Winter Title

Wheat in Petrovskiy Rayon of the Stavropol'skiy Krai

: Materialy po izuch. Stavropol'sk. kraya. Vyp. 8, 1956, Orig Pub

33-41

The results of observations made at the Petrovsk Agri-Abstract

cultural Meteorological station on the chief stages in the development of winter wheat. The article examines the problems of the sowing periods, conditions of wintering, spring-summer conditions of vegetation, agricultural technique in 1943-1946 and in 1947-1955, and the har-

vesting of the crop.

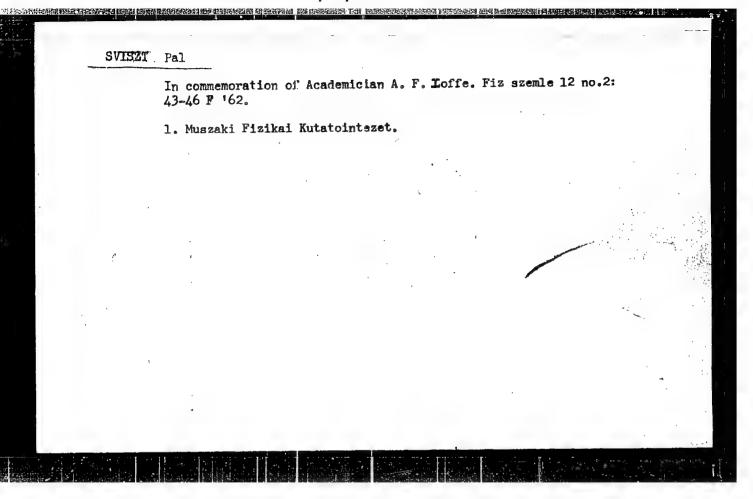
Card 1/1

- 9

SVISZT, Pal

In commemoration of M. V. Lomonosov; on his 250th birthday. Fiz szemle 11 no.11:337-340 N '61.

1. Magyar Tudomany)s Akademia Muszaki Fizikai Kutato Intezete, Budapest.



SVISZT, P.; SCHANDA, J.

Some remarks on the photoelectroluminescence of ZnS single crystals. Acta plys Hung 14 no.2 3:121-125 '62.

l. Research Institute for Technical Physics of the Hungarian Academy of Sciences, Budapest. Presented by G. Szigeti [Gyorgy Sziegti]

SVISZT, P.

Narrow bands of the huminescence of CuBr and of alkali halide phosphors activated by CuBr. Acta phys Hung 14 no.2 3:283-294 *62.

1. Research Institute for Technical Physics of the Hungarian Academy of Sciences, Budapest. Presented by G. Szigeti [Gyorgy Szigeti]

SVISET, P.

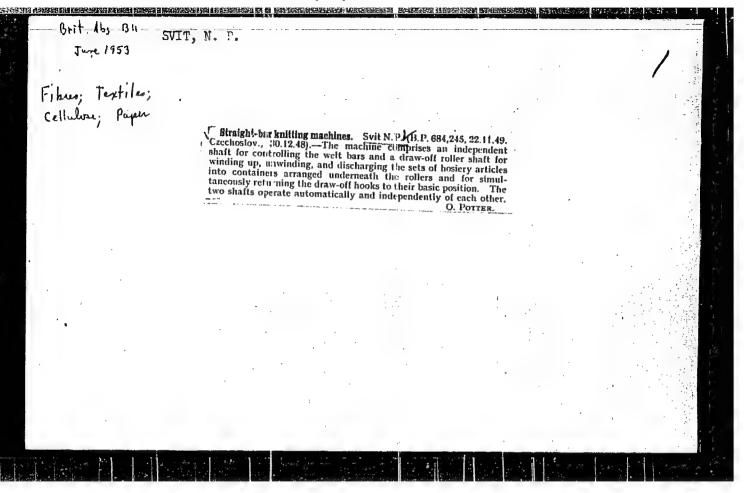
Ultraviolet irradiation of ZnS single crystals kept in the atmosphere of various gases. Chekhosl fiz shurnal 13 no.2:88-90 '63.

1. Research Institute for Technical Physics, Hungarian Academy of Sciences, Budapest, Hungary;

SVISZT, P.

On the darkening of ZnS single crystals by light. Acta physica Pol 26 no.3/4:823-827 S-0 '64.

1. Research Institute for Technical Physics of the Hungarian Academy of Sciences, Budapest.



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GALAKTIONOV, A.T., kand. tekhn. nauk; SVIT, P.P., inzh.; FOFANOV, A.A., kand. tekhn. nauk

Modernizing the ASIF-25 machine, Svar. proizv. no.8:38-39 Ag '63. (MIRA 17:1)

1. Ural'skiy politekhnicheskiy institut im. S.M. Kirova.

SVIT, P.P., inzh.; FOFANOV, A.A., kand.tekhn.nauk; ZHURAVLEV, L.G., kand. tekhn.nauk

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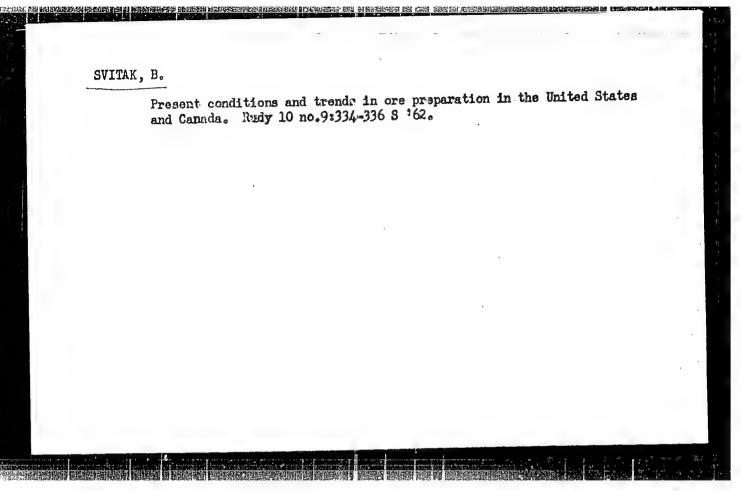
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Internal conversion from the fluorescent to the phosphorescent level in naphthalene derivatives. Izv.AN SSSR.Ser.fiz. 24 no.5:492-495 by 160. (MIRA 13:5) (Naphthalene-Optical properties) (Luminescence)

-	L 22914-66 EWT(m)/EWP(t) IJP(c) JD/JG ACC NR: AP6009657 SOURCE CODE: UR/0181/66/008/003/0758/0766	
	AUTHORS: Rzhanov, A. V.; Svitashev, K. K.; Filatova, Ye. S.; 64 Shepel', V. M.	
	ORG: <u>Institute of Semiconductors, SO AN SSSR, Novosibirsk</u> (Institut poluprovodnikov SO AN SSSR)	
	TITLE: Investigation of the surface photoconductivity of germanium	
	SOURCE: Fizika tverdogo tela, v. 8, no. 3, 1966, 758-766	
	TOPIC TAGS: germanium, photoconductivity, surface property, semi- conductor conductivity, semiconductor impurity, forbidden band, spectral energy distribution	
	ABSTRACT: This is a continuation of earlier work (FTT v. 3, 1557, 1961) dealing with impurity photoconductivity and the concentration of photoactive surface defects. The present investigation was made with p-type germanium doped with gallium, and having a specific resistivity 20 30 ohm cm and a carrier lifetime ~800 µsec. The	
	samples were placed in a cryostat in vacuum 5 x 10 torr and exposed	
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to monochromatic radiation from the IKS-12 instrument. Measurements were made of the temperature and spectral dependences of the surface photoconductivity and also of its time lag. The impurity photoconductivity of a thin sample of germanium was measured with light modulated at 12 cps. No impurity photoconductivity was observed at room temperature and at dry ice temperature, but was observed at liquid nitrogen temperature (- 1700), at which all other measurements The results demonstrated once more the existence of a specific photoconductivity in germanium, connected with excitation of The experimental reasons for this conclusion are surface defects. presented in detail. The results also show that it is possible in principle to obtain data on the energy levels of the photoactive surface defects in the forbidden band of the semiconductor by analyzing the surface-photoconductivity spectra. Further data can be expected from these results if the surface potential can be determined by an independent method and the spectral resolution is improved. Work is continued in this direction. Orig. art. has: 12 figures, 3 formulas, and 1 table.

SUB CODE: 20/ SUBM DATE: 20Ju165/ ORIG REF: 003/ OTH REF: 005

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ACC NR. A16018576

SOURCE CODE: UR/0181/66/008/006/1955/1957

AUTHOR: Rzhanov, A. V.; Svitashev, K. K.; Shepel', V. M.

ORG: Institute of Physics of Semiconductors, SO AN SSSR, Novosibirsk (Institut fiziki poluprovodnikov SO AN SSSR)

TITLE: Influence of capture of nonequilibrium carriers by surface defects on the spectrum of the intrinsic photoconductivity of a thin sample of germanium

SOURCE: Fizika tverdogo tela, v. 8, no. 6, 1966, 1955-1957

TOPIC TAGS: photoconductivity, germanium semiconductor, capture cross section

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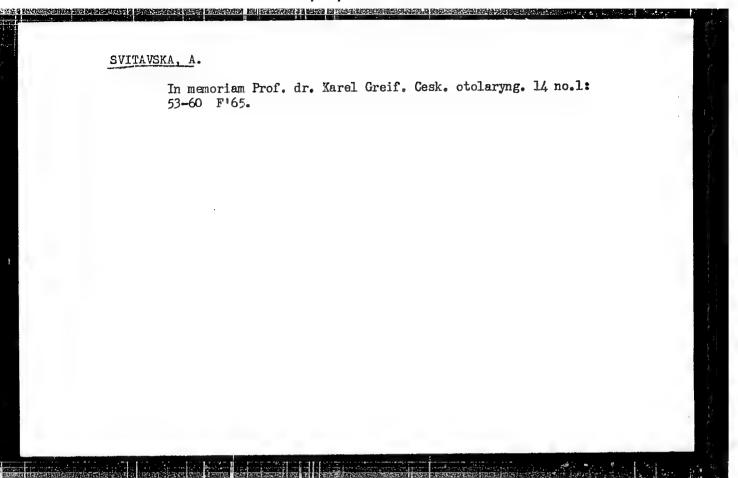
ABSTRACT: The authors compare the pulses of intrinsic photoconductivity of thick and thin samples of p-type germanium at liquid-nitrogen temperature. The shape of the photoconductivity pulse of the thin sample exhibited singularities characteristic of the presence of traps. It is shown that the total change of the conductivity of the sample under the influence of the light consists of three factors (photoconductivity proper, change in surface conductivity as a result of change in carrier density, and change in surface conductivity as a result of change of the surface charge), and in the region of 1.64 μ the contribution of the third process is comparable in magnitude with the contributions of the first two. The additional illumination, which normally eliminates adhesion of nonequilibrium carriers on the germanium surface at low temperatures, reduced the photoconductivity of the thin germanium to approximately the same value as that of thick germanium (5 vs. 0.5 mm) and eliminated the peak at 1.64 μ

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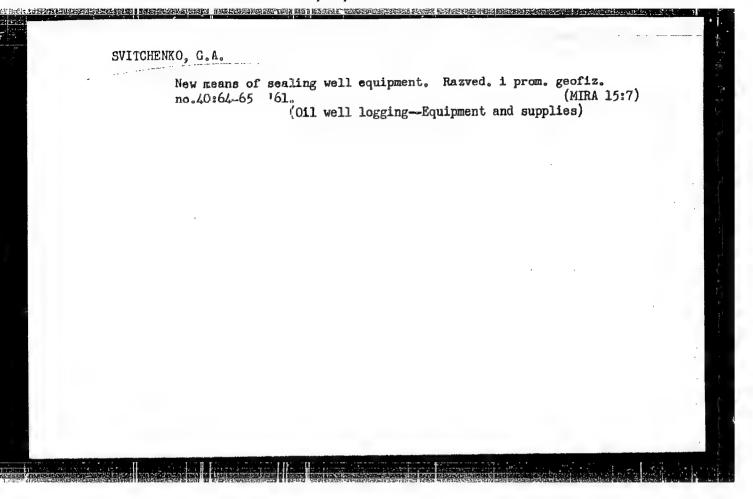
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(PSYCHOPHARMACOLOGY)

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USSR COUNTRI Н : Weeds and Weed Control. CATEGORY : EZhBiol., No. 3, 1959, No. 11220 ABS. JOUR. : Svitek, I. AUTHOR. Sandbatting Standard : "Dikotex-30" - A Proparation for the Destruction of IMST. TITLE Weeds in the Flax and Grain Sowings. ORIG. PUB, : Len i konoplya, 1958, No. 5, 46-43 : The preparation "dikotex-30" (30% potash salt of 2-methyl 4-chlorophenoxyacetic acid) (I) made in Czechoulovakia ABSTRACT for the control of weeds in flax and grain sowings is obtained by means of the colorination of orthograsol and by the condensation of the salt of the chlorinated cresol with monochloroacetate of potassium. Owing to the use of (I), the expenditures for the weeding of flex are reduced by 31% and the yield of straw is increased by 30%. The quality of the delivered straw was raised from grade 3 to grade 6; the marketable length of the straw increas-[GARD: 1/4 _2-

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